

DUAL SUPPLY, LOW ON-STATE RESISTANCE SPST CMOS ANALOG SWITCHES

FEATURES

- ± 1 -V to ± 6 -V Dual-Supply Operation
- Specified ON-State Resistance:
 - 25 Ω Max With ± 5 -V Supply
 - 35 Ω Max With ± 3.3 -V Supply
 - 47 Ω Max With ± 1.8 -V Supply
- Specified Low OFF-Leakage Currents:
 - 5 nA at 25°C
 - 10 nA at 85°C
- Specified Low ON-Leakage Currents:
 - 5 nA at 25°C
 - 10 nA at 85°C
- Low Charge Injection: 13 pC (± 5 -V Supply)
- Fast Switching Speed:
 - $t_{ON} = 85$ ns, $t_{OFF} = 50$ ns (± 5 -V Supply)
- Break-Before-Make Operation ($t_{ON} > t_{OFF}$)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2500-V Human-Body Model (A114-F)
 - 1000-V Charged-Device Model (C101-C)
 - 250-V Machine Model (A115-A)

DESCRIPTION/ORDERING INFORMATION

The TS12A4516/TS12A4517 are single pole/single throw (SPST), low-voltage, dual-supply CMOS analog switches, with very low switch ON-state resistance. The TS12A4516 is normally open (NO). The TS12A4517 is normally closed (NC).

These CMOS switches can operate continuously with a dual supplies between ± 1 V and ± 6 V [2 V $< (V_+ - V_-) < 12$ V]. Each switch can handle rail-to-rail analog signals. The OFF-leakage current maximum is only 5 nA at 25°C or 10 nA at 85°C.

For pin-compatible parts for use with single supply, see the TS12A4514/TS12A4515.

ORDERING INFORMATION

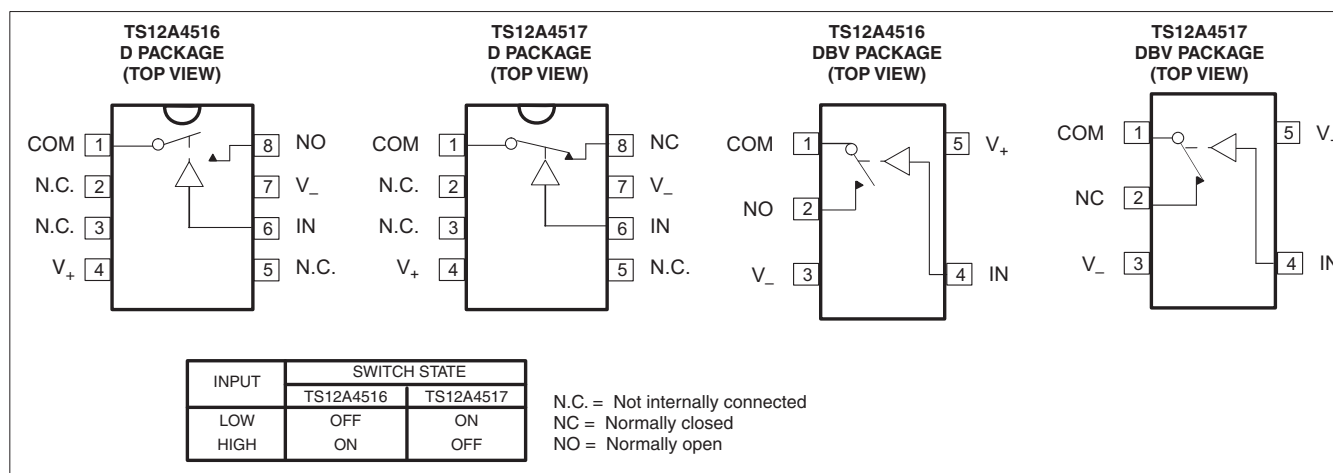
T_A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	SOIC – D	Reel of 1500	TS12A4516D	YD516
		Reel of 2500	TS12A4516DR	
	SOP (SOT-23) – DBV	Reel of 3000	TS12A4516DBVR	9CL_
	SOIC – D	Reel of 1500	TS12A4517D	YD517
		Reel of 2500	TS12A4517DR	
	SOP (SOT-23) – DBV	Reel of 3000	TS12A4517DBVR	9CM_

- (1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



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PIN CONFIGURATIONS

Absolute Minimum and Maximum Ratings⁽¹⁾⁽²⁾

voltages referenced to 0 V

		MIN	MAX	UNIT
V ₊	Supply voltage range	−0.3	13	V
V _{NC} V _{NO} V _{COM}	Analog voltage range ⁽³⁾	V _− −0.3	V ₊ + 0.3	V
V _{IN}	Logic input range	V _− −0.3	V ₊ + 0.3	V
Continuous current into any terminal		±20		mA
Peak current, NO or COM (pulsed at 1 ms, 10% duty cycle)		±30		mA
ESD per method 3015.7		>2000		V
Continuous power dissipation (T _A = 70°C)		8-pin SOIC (derate 5.88 mW/°C above 70°C)	471	mW
		5-pin SOT23-5 (derate 7.1 mW/°C above 70°C)	571	
T _A	Operating temperature range	−40	85	°C
T _{stg}	Storage temperature range	−65	150	°C
Lead temperature (soldering, 10 s)		300		°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) Voltages exceeding V₊ or GND on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Electrical Characteristics for ± 5 -V Supply⁽¹⁾

 $V_+ = 4.5 \text{ V to } 5.5 \text{ V}$, $V_- = -4.5 \text{ V to } -5.5 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			V ₋		V ₊	V
ON-state resistance	r _{on}	V ₊ = 4.5 V, V ₋ = −4.5 V, V _{COM} = 3.5 V, I _{COM} = 20 mA	25°C	12		20	Ω
			Full			25	
ON-state resistance flatness	r _{on(flat)}	V ₊ = 4.5 V, V ₋ = −4.5 V, V _{COM} = −3.5 V, 0 V, 3.5 V, I _{COM} = 20 mA	25°C	1.2		2.5	Ω
			Full			3	
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 5.5 V, V ₋ = −5.5 V, V _{COM} = 4.5 V, V _{NO} or V _{NC} = −4.5 V	25°C			5	nA
			Full			10	
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 5.5 V, V ₋ = −5.5 V, V _{COM} = −4.5 V, V _{NO} or V _{NC} = 4.5 V	25°C			5	nA
			Full			10	
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 5.5 V, V ₋ = −5.5 V, V _{COM} = 5.5 V, V _{NO} or V _{NC} = open	25°C			5	nA
			Full			10	
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	V ₊ − 1.5			V
Input logic low	V _{IL}		Full	V ₋		V ₊ − 3.5	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.010	μA
Dynamic							
Turn-on time	t _{ON}	See Figure 2	25°C	58		75	ns
			Full			85	
Turn-off time	t _{OFF}	See Figure 2	25°C	28		45	ns
			Full			50	
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, V _{NO} = 0 V, R _S = 0 Ω, See Figure 1	25°C	−13			pC
NO, NC OFF capacitance	C _{NO(OFF)} , C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C	5.5			pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C	5.5			pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C	16			pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C	1.5			pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	464			MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 1 MHz	25°C	−83			dB
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 20 kHz	25°C	0.07			%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C			70	μA
			Full			80	
V ₋ supply current	I ₋	V _{IN} = 0 V or V ₊	25°C	−70			μA
			Full	−80			

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.

(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

Electrical Characteristics for ± 3.3 -V Supply⁽¹⁾
 $V_+ = 3.0 \text{ V to } 3.6 \text{ V}$, $V_- = -3.0 \text{ V to } -3.6 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			V ₋		V ₊	V
ON-state resistance	r _{on}	V ₊ = 3.0 V, V ₋ = −3.0 V, V _{COM} = 3 V, I _{COM} = 20 mA	25°C		17	25	Ω
			Full			35	
ON-state resistance flatness	r _{on(flat)}	V _{COM} = −2 V, 0 V, 2 V, I _{COM} = 20 mA	25°C		1.5	3	Ω
			Full			4	
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 3.6 V, V ₋ = −3.6 V, V _{COM} = 3 V, V _{NO} or V _{NC} = −3 V	25°C			5	nA
			Full			10	
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 3.6 V, V ₋ = −3.6 V, V _{COM} = −3 V, V _{NO} or V _{NC} = 3 V	25°C			5	nA
			Full			10	
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 3.6 V, V ₋ = −3.6 V, V _{COM} = 3.6 V, V _{NO} or V _{NC} = open	25°C			5	nA
			Full			10	
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	V ₊ − 1.5			V
Input logic low	V _{IL}		Full	V ₋		V ₊ − 3.5	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.01	μA
Dynamic							
Turn-on time	t _{ON}	see Figure 2	25°C		65	85	ns
			Full			95	
Turn-off time	t _{OFF}	see Figure 2	25°C		37	60	ns
			Full			70	
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, V _{NO} = 0 V, R _S = 0 Ω, See Figure 1	25°C		−7.5		pC
NO, NC OFF capacitance	C _{NO(OFF)} C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C		5.5		pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C		5.5		pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C		16		pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C		1.5		pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C		464		MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C		−83		dB
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 20 kHz	25°C		0.10		%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C			40	μA
			Full			45	
V ₋ supply current	I ₋	V _{IN} = 0 V or V ₊	25°C		−40		μA
			Full		45		

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

Electrical Characteristics for ± 1.8 -V Supply⁽¹⁾

 $V_+ = 1.65 \text{ V to } 1.95 \text{ V}$, $V_- = -1.65 \text{ V to } -1.95 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			V ₋		V ₊	V
ON-state resistance	r _{on}	V ₊ = 1.65 V, V ₋ = −1.65 V, V _{COM} = 0 V, I _{COM} = 20 mA	25°C	28		40	Ω
			Full			47	
ON-state resistance flatness	r _{on(flat)}	V ₊ = 1.65 V, V ₋ = −1.65 V, V _{COM} = −1.8 V, 0 V, 1.5 V, I _{COM} = 20 mA	25°C	9		13	Ω
			Full			15	
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 1.95 V, V ₋ = −1.95 V, V _{COM} = 1.65 V, V _{NO} or V _{NC} = −1.65 V	25°C			5	nA
			Full			10	
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 1.95 V, V ₋ = −1.95 V, V _{COM} = −1.65 V, V _{NO} or V _{NC} = 1.65 V	25°C			5	nA
			Full			10	
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 1.95 V, V ₋ = −1.95 V, V _{COM} = 1.95 V, V _{NO} or V _{NC} = open	25°C			5	nA
			Full			10	
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	V ₊ − 1.5			V
Input logic low	V _{IL}		Full	V ₋		V ₊ − 3.5	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.01	μA
Dynamic							
Turn-on time ⁽⁴⁾	t _{ON}	See Figure 2	25°C	90		120	ns
			Full			150	
Turn-off time ⁽⁴⁾	t _{OFF}	See Figure 2	25°C	95		150	ns
			Full			200	
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, See Figure 1	25°C	−3.5			pC
NO, NC OFF capacitance	C _{NO(OFF)} , C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C	6			pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C	6			pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C	14.5			pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C	1.5			pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	464			MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 1 MHz	25°C	−83			dB
Total harmonic distortion	THD	R _L = 600 Ω, C _L = 50 pF, V _{NO} = 1 V _{RMS} , f = 20 kHz	25°C	0.37			%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C			20	μA
			Full			30	
V ₋ supply current	I ₋	V _{IN} = 0 V or V ₊	25°C	−20			μA
			Full	−30			

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.

(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

PIN DESCRIPTION⁽¹⁾

PIN NO.				NAME	DESCRIPTION
TS12A4516		TS12A4517			
D, P	SOT23-5	D, P	SOT23-5		
1	1	1	1	COM	Common
2, 3, 5	–	2, 3, 5	–	N.C.	No connect (not internally connected)
4	5	4	5	V ₊	Positive power supply
6	4	6	4	IN	Digital control to connect COM to NO or NC
7	3	7	3	V _–	Negative power supply
8	2	–	–	NO	Normally open
–	–	8	2	NC	Normally closed

(1) NO, NC, and COM pins are identical and interchangeable. Any may be considered as an input or an output; signals pass in both directions.

APPLICATION INFORMATION

Power-Supply Considerations

The TS12A4516 and TS12A4517 operate with power-supply voltages from ± 1 V to ± 6 V [$(2\text{ V} < (V_+ - V_-) < 12\text{ V})$], but are tested and specified at ± 5 V, ± 3.3 V, and ± 1.8 V supplies. The pin-compatible TS12A4514 and TS12A4515 are recommended for use when only a single supply is desirable.

The TS12A4516 and TS12A4517 construction is typical of most CMOS analog switches, except that they have only two supply pins: V_+ and V_- . V_+ and V_- drive the internal CMOS switches and set their analog voltage limits. Reverse ESD-protection diodes are internally connected between each analog-signal pin and both V_+ and V_- . One of these diodes conducts if any analog signal exceeds V_+ or V_- .

Virtually all the analog leakage current comes from the ESD diodes to V_+ or V_- . Although the ESD diodes on a given signal pin are identical and, therefore, fairly well balanced, they are reverse biased differently. Each is biased by either V_+ or V_- and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V_+ and V_- pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of the same or opposite polarity.

V_+ and V_- also power the internal logic and logic-level translators. The logic-level translators convert the logic levels to switched V_+ and V_- signals to drive the analog signal gates.

Logic-Level Thresholds

Since these parts have no ground pin, the logic-level threshold is referenced to V_+ . The threshold limits are $V_+ - 1.5$ V and $V_+ - 3.5$ V for V_+ levels between 6 V and 3 V. When $V_+ = 2$ V, the logic threshold is approximately 0.6 V.

CAUTION:

Do not connect the TS12A4516/TS12A4517 V_+ to 3 V and then connect the logic-level pins to logic-level signals that operate from 5-V supply. TTL levels can exceed 3 V and violate the absolute maximum ratings, damaging the part and/or external circuits.

Test Circuits/Timing Diagrams

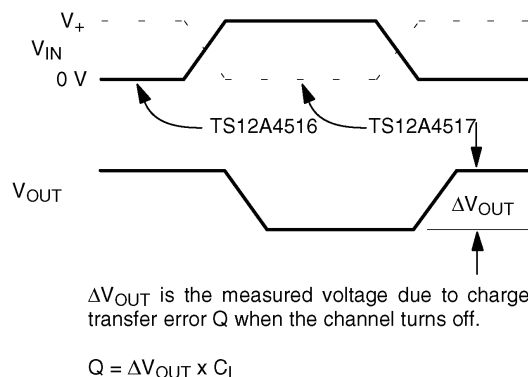
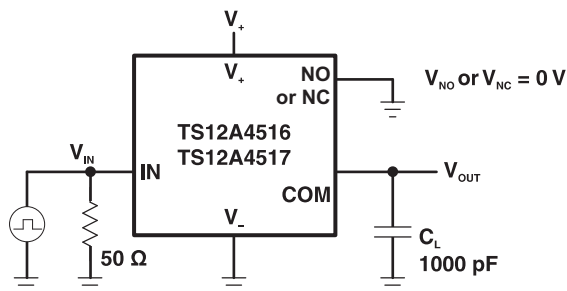
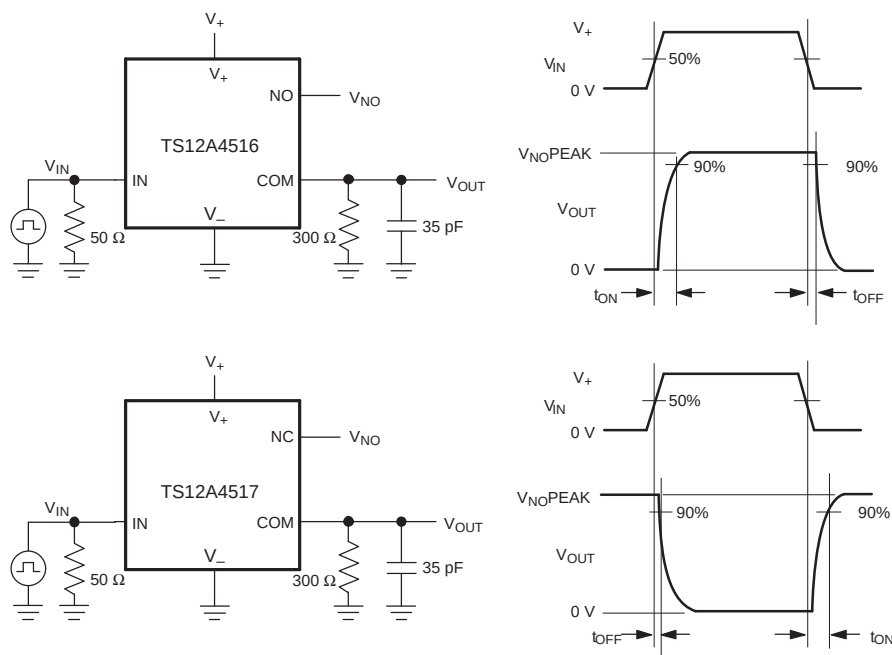
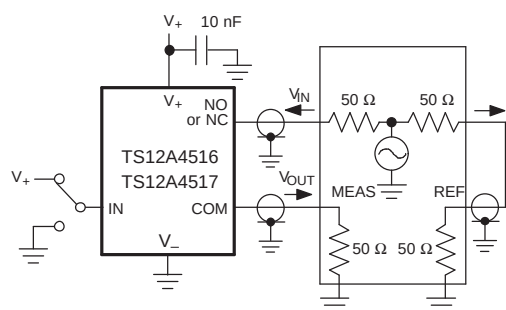


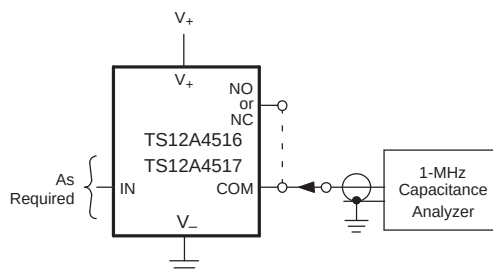
Figure 1. Charge Injection

**Figure 2. Switching Times**

Measurements are standardized against short at socket terminals. OFF isolation is measured between COM and OFF terminals on each switch. ON loss is measured between COM and ON terminals on each switch. Signal direction through switch is reversed; worst values are recorded.

$$\text{OFF Isolation} = 20 \log \frac{V_{OUT}}{V_{IN}}$$

$$\text{ON Loss} = 20 \log \frac{V_{OUT}}{V_{IN}}$$

Figure 3. OFF Isolation and ON Loss**Figure 4. NO, NC, and COM Capacitance**

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS12A4516D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4516D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4516D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4516DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CLA, 9CLM)
TS12A4516DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CLA, 9CLM)
TS12A4516DBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CLA, 9CLM)
TS12A4516DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CLA
TS12A4516DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CLA
TS12A4516DBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CLA
TS12A4516DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4516DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4516DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD516
TS12A4517D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517
TS12A4517D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517
TS12A4517D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517
TS12A4517DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CMA, 9CMM)
TS12A4517DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CMA, 9CMM)
TS12A4517DBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(9CMA, 9CMM)
TS12A4517DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CMA
TS12A4517DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CMA
TS12A4517DBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CMA
TS12A4517DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517
TS12A4517DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517
TS12A4517DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD517

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

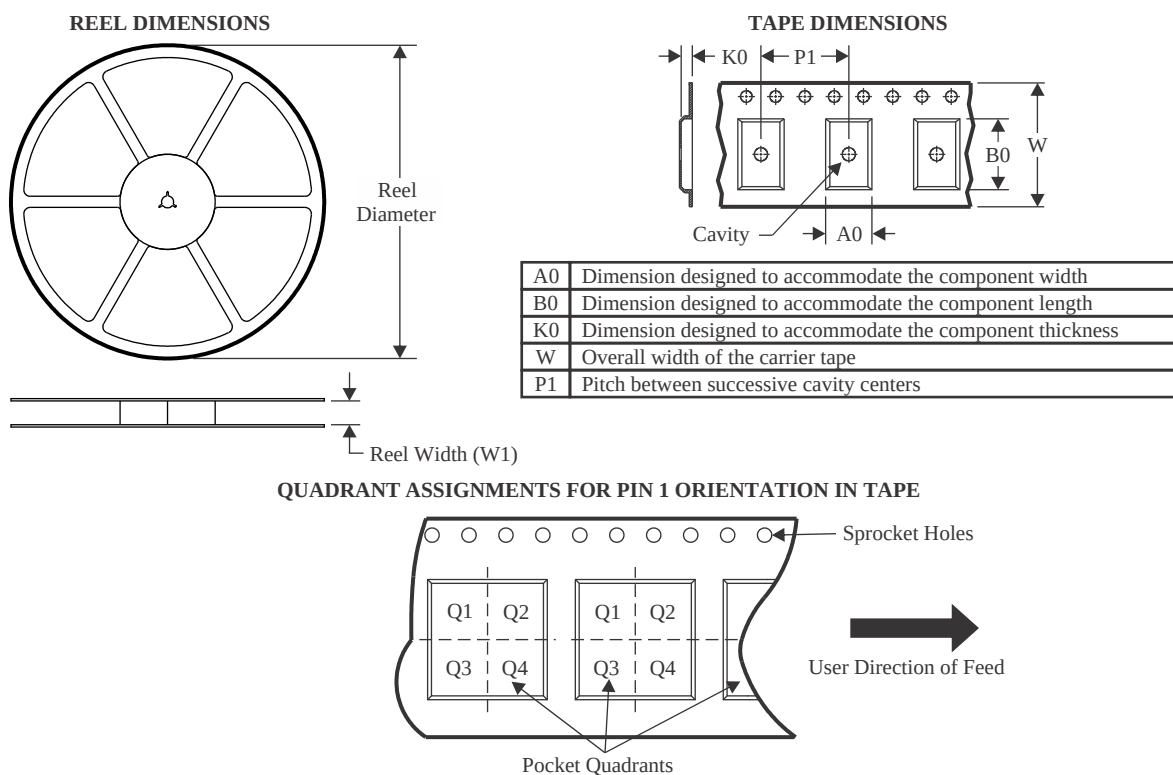
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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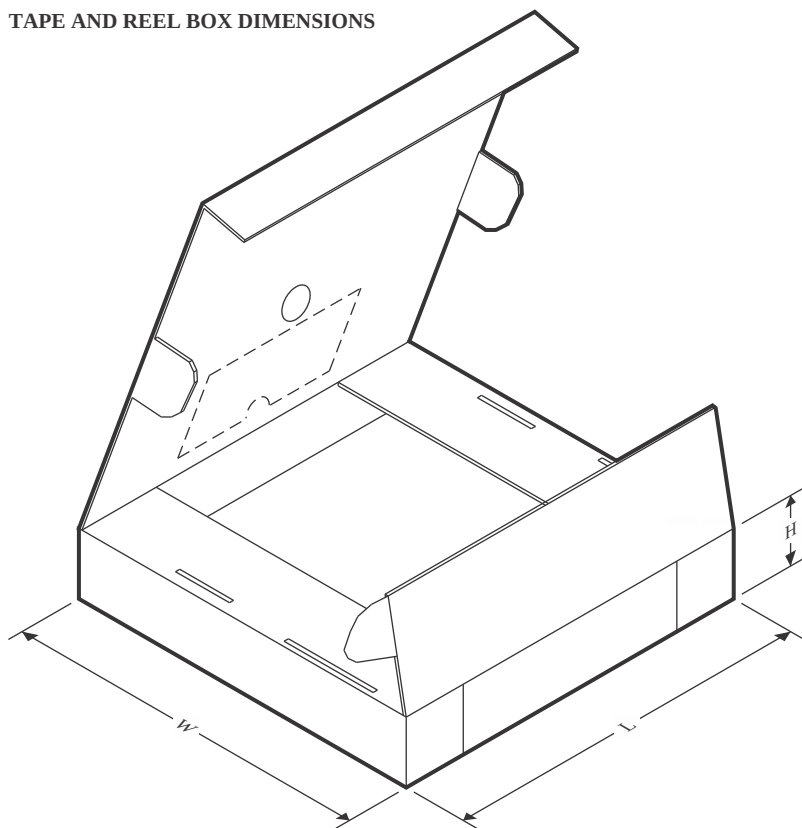
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS12A4516DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TS12A4516DBVRG4	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TS12A4516DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TS12A4517DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

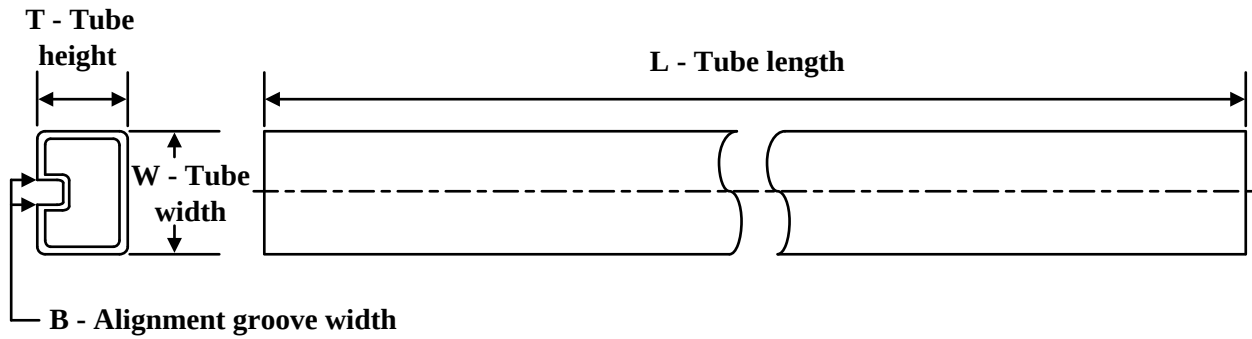
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS12A4516DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
TS12A4516DBVRG4	SOT-23	DBV	5	3000	202.0	201.0	28.0
TS12A4516DR	SOIC	D	8	2500	353.0	353.0	32.0
TS12A4517DR	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TS12A4516D	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4516D.A	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4516D.B	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4517D	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4517D.A	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4517D.B	D	SOIC	8	75	506.6	8	3940	4.32



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

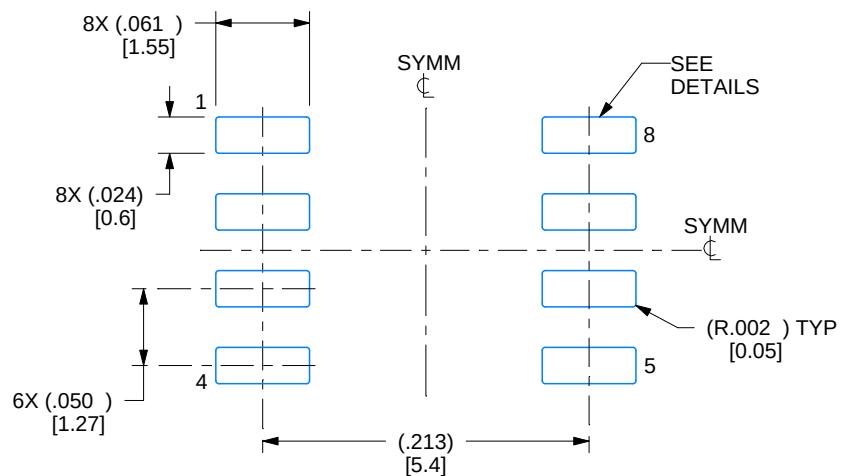


1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

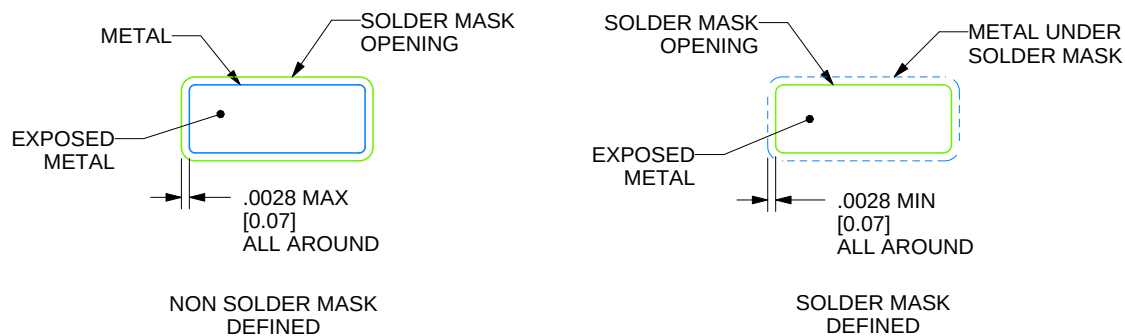
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

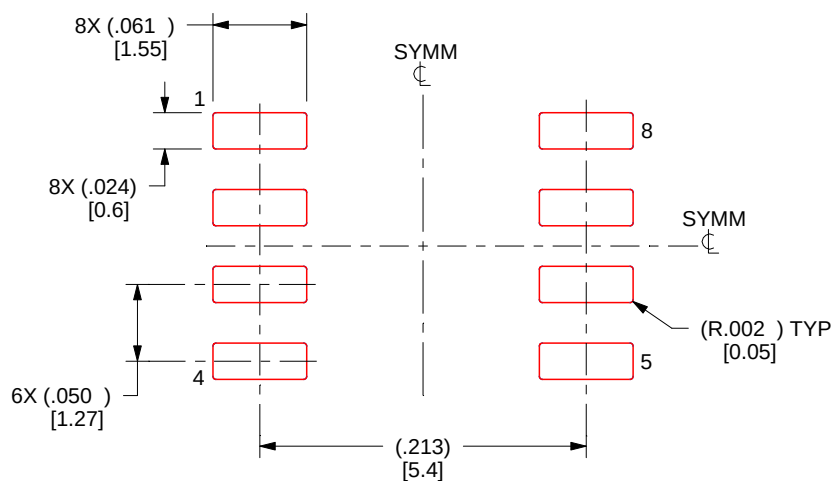
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

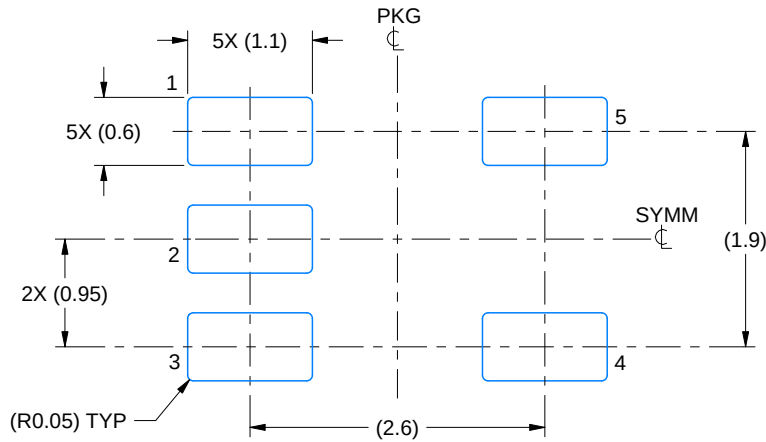
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

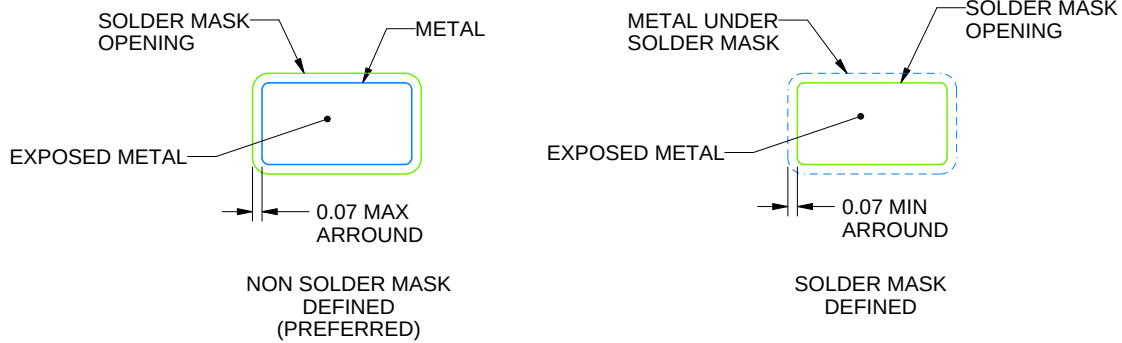
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

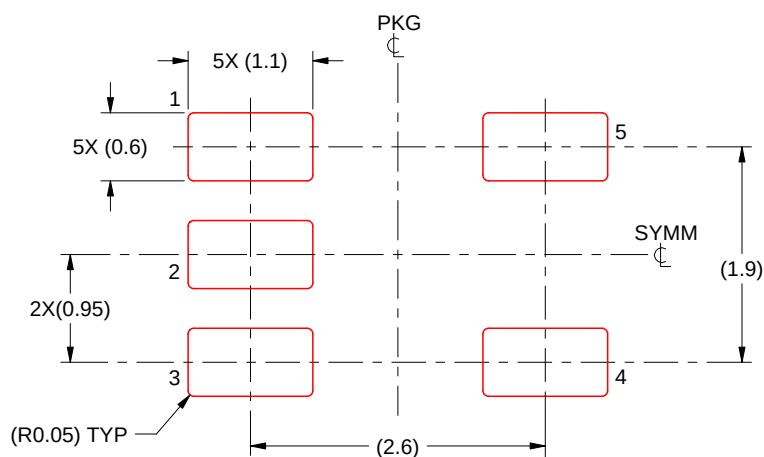
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025